

**JX080K 8A Sensitive SCR**

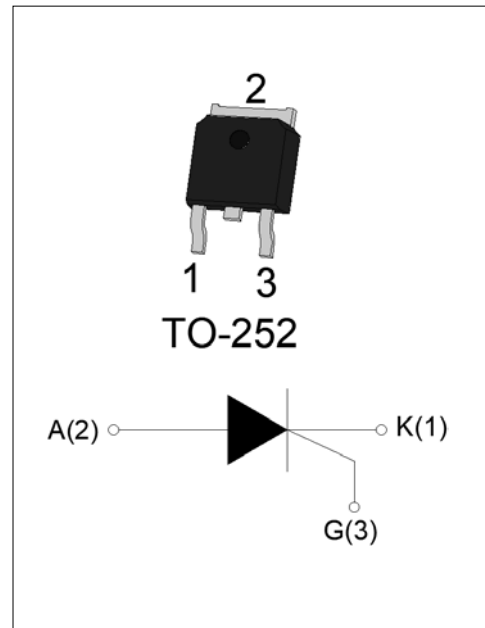
Rev.A.1.1

DESCRIPTION:

The JX080K SCR provides high dV/dt rate with strong resistance to electromagnetic interface. It is especially recommended for use on residual current circuit breaker, straight hair, igniter etc. Package TO-252 is RoHS compliant.

MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	8	A
V_{DRM}/V_{RRM}	800	V
I_{GT}	≤ 200	μA

**ABSOLUTE MAXIMUM RATINGS**

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40-150	$^{\circ}C$
Operating junction temperature range	T_j	-40-110	$^{\circ}C$
Repetitive peak off-state voltage ($T_j=25^{\circ}C$)	V_{DRM}	800	V
Repetitive peak reverse voltage ($T_j=25^{\circ}C$)	V_{RRM}	800	V
Average on-state current ($T_c \leq 55^{\circ}C$)	$I_{T(AV)}$	5	A
RMS on-state current ($T_c \leq 55^{\circ}C$)	$I_{T(RMS)}$	8	A
Non repetitive surge peak on-state current ($t_p=10ms$, $T_j=25^{\circ}C$)	I_{TSM}	80	A
Non repetitive surge peak on-state current ($t_p=8.3ms$, $T_j=25^{\circ}C$)		88	
I^2t value for fusing ($t_p=10ms$, $T_j=25^{\circ}C$)	I^2t	32	A^2s
Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$, $f=100Hz$, $T_j=110^{\circ}C$)	di/dt	100	$A/\mu s$
Peak gate current ($t_p=20\mu s$, $T_j=110^{\circ}C$)	I_{GM}	4	A
Average gate power dissipation ($T_j=110^{\circ}C$)	$P_{G(AV)}$	1	W
Peak gate power	P_{GM}	10	W

Peak pulse voltage ($T_j=25^{\circ}\text{C}$; non-repetitive, off-state; FIG.8)	V_{pp}	0.5	kV
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ELECTRICAL CHARACTERISTICS ($T_j=25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Test Condition	Value			Unit
		MIN.	TYP.	MAX.	
I_{GT}	$V_D=12\text{V}$ $R_L=33\Omega$	-	60	200	μA
V_{GT}		-	-	0.8	V
V_{GD}	$V_D=V_{DRM}$ $T_j=110^{\circ}\text{C}$	0.2	-	-	V
I_L	$I_G=1.2 I_{GT}$	-	-	6	mA
I_H	$I_T=0.05\text{A}$	-	-	5	mA
dV/dt	$V_D=540\text{V}$ $T_j=110^{\circ}\text{C}$ $R_{GK}=1\text{k}\Omega$	50	-	-	$\text{V}/\mu\text{s}$
	$V_D=540\text{V}$ $T_j=110^{\circ}\text{C}$ $R_{GK}=220\Omega$	200	-	-	
t_{on}	$I_G=10\text{mA}$ $I_A=20\text{mA}$ $I_R=2\text{mA}$ $T_j=25^{\circ}\text{C}$	-	2	-	μs
t_{off}		-	70	-	μs

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	$I_T=16\text{A}$ $t_p=380\mu\text{s}$	$T_j=25^{\circ}\text{C}$	1.6	V
V_{TO}	Threshold voltage	$T_j=110^{\circ}\text{C}$	0.79	V
R_D	Dynamic Resistance	$T_j=110^{\circ}\text{C}$	0.04	Ω
I_{DRM}	$V_D=V_{DRM}$ $V_R=V_{RRM}$	$T_j=25^{\circ}\text{C}$	5	μA
I_{RRM}		$T_j=110^{\circ}\text{C}$	0.5	mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (DC)	5	$^{\circ}\text{C}/\text{W}$
$R_{th(j-a)}$	junction to ambient (DC)	120	$^{\circ}\text{C}/\text{W}$

ORDERING INFORMATION

J	X	080	K	-/
JieJie Microelectronics Co., Ltd.				Blank: Tube -TR: Tape & Reel
Sensitive gate SCRs				
		IT(RMS):8A		
			K:TO-252	

MARKING

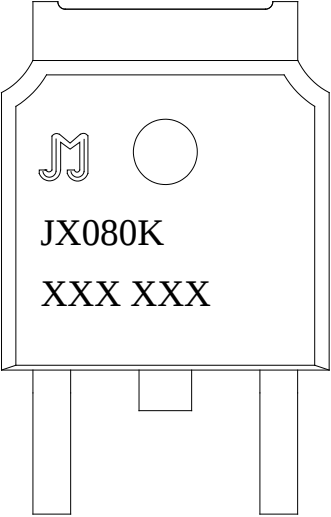
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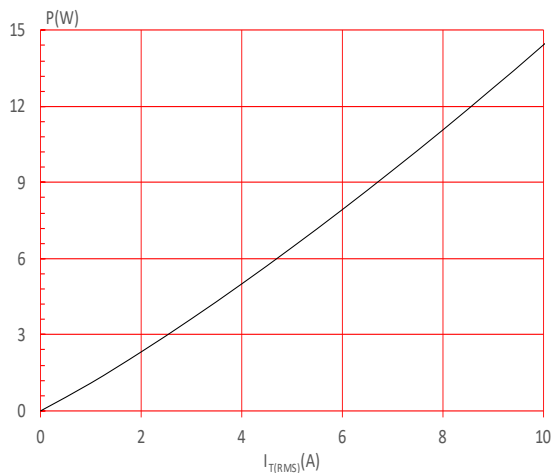
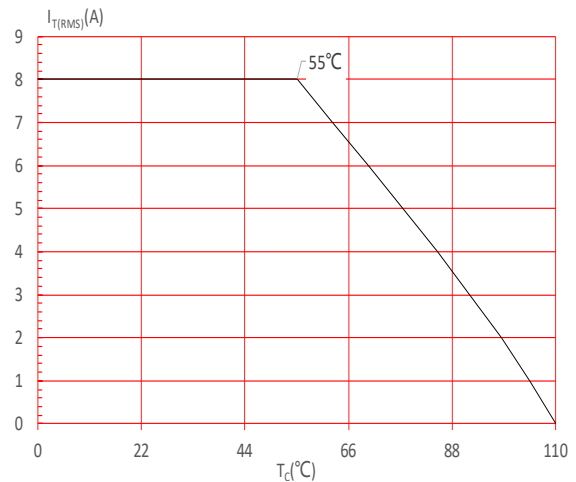
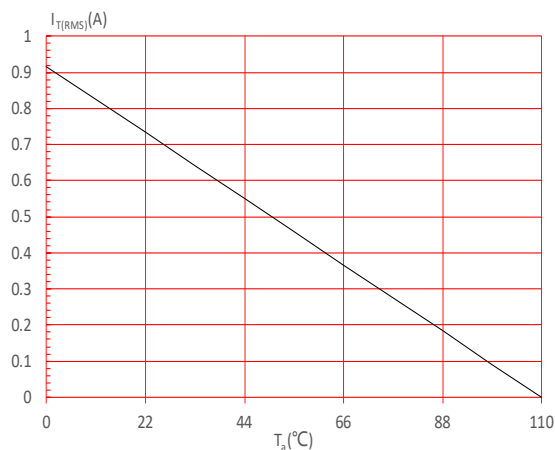
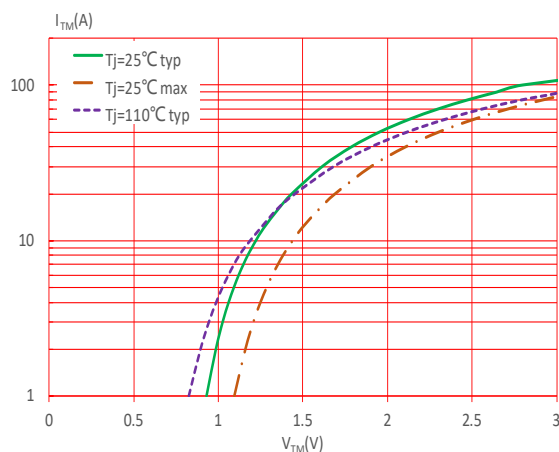
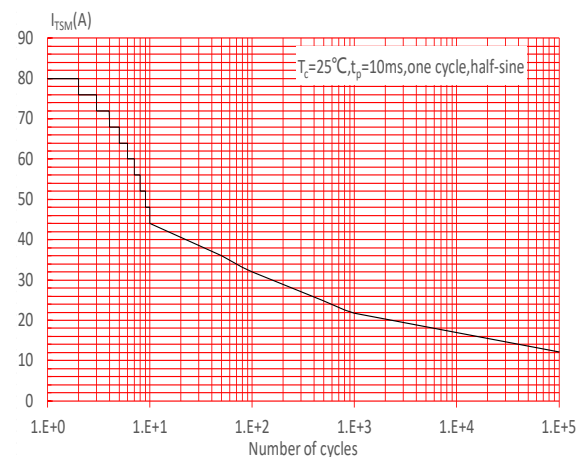
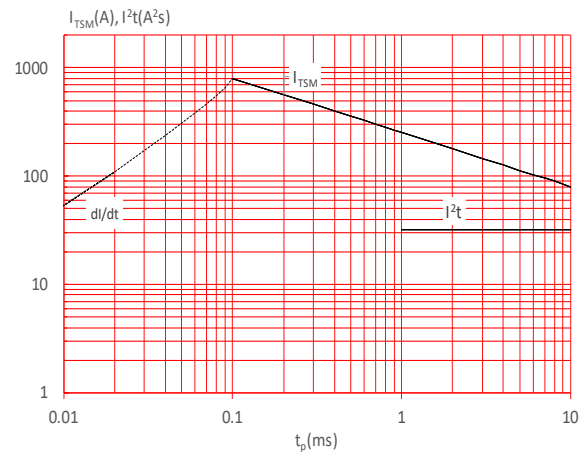
FIG.1: Maximum power dissipation versus RMS on-state current

FIG.2: RMS on-state current versus case temperature

FIG.3: RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness:35μm)(full cycle)

FIG.5: On-state characteristics

FIG.4: Surge peak on-state current versus number of cycles

FIG.6: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10ms$, and corresponding value of I^2t ($di/dt < 100A/μs$)


FIG.7: Relative variations of gate trigger current, holding current and latching current versus junction temperature

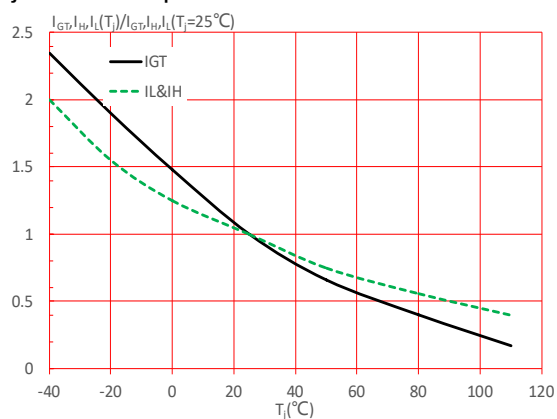
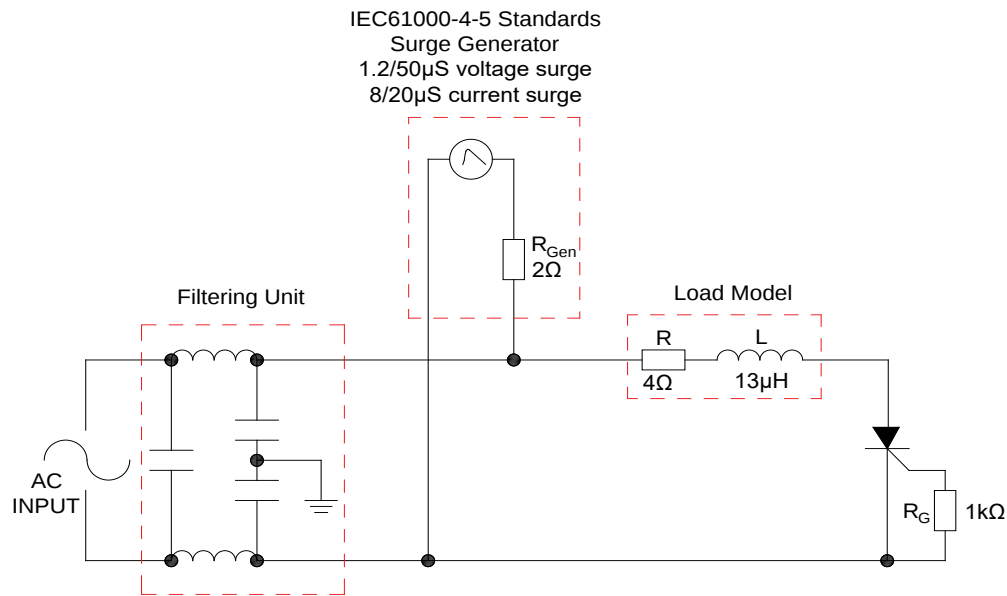
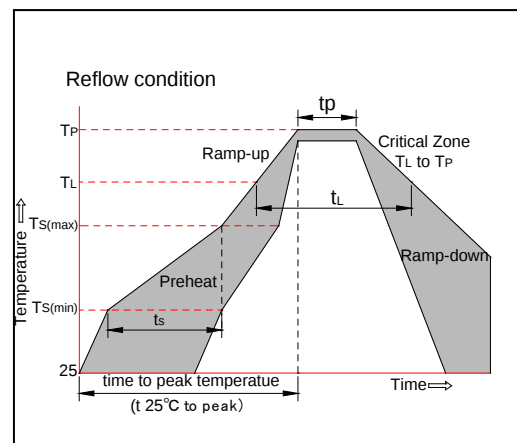


FIG.8: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards.



SOLDERING PARAMETERS

Reflow Condition		Pb-Free assembly (see figure at right)
Pre Heat	-Temperature Min (T _{S(min)})	+150°C
	-Temperature Max (T _{S(max)})	+200°C
	-Time (Min to Max) (t _s)	60-180 secs.
Average ramp up rate (Liquidus Temp (T _L) to peak)		3°C/sec. Max
T _{S(max)} to T _L - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature(T _L) (Liquidus)	+217°C
	-Temperature(t _L)	60-150 secs.
Peak Temp (T _p)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (t _p)		20-40secs.
Ramp-down Rate		6°C/sec. Max
Time 25°C to Peak Temp (T _p)		8 min. Max
Do not exceed		+260°C



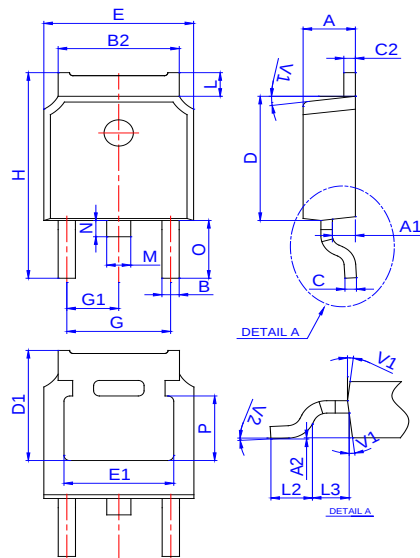
ORDERING INFORMATION

Order code	Voltage $V_{\text{DRM}}/V_{\text{RRM}}$ (V)	IGT(μA)	Package	Base qty. (pcs)	Delivery mode
JX080K	800	≤ 200	TO-252	80	Tube
JX080K-TR				2,500	Tape & Reel

Document Revision History

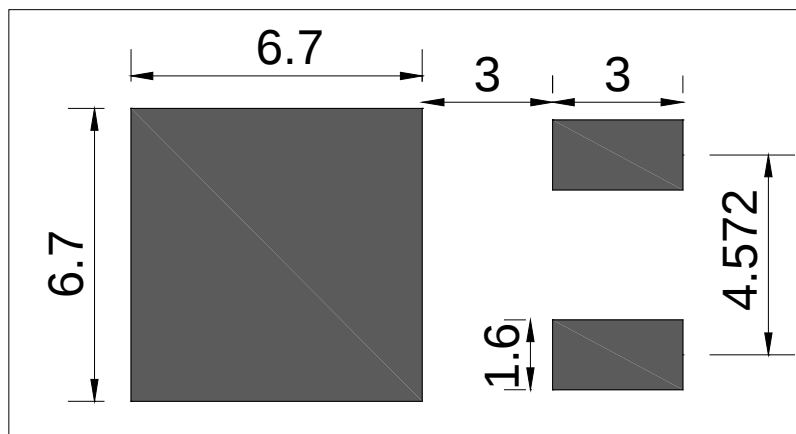
Date	Revision	Changes
May 18, 2023	A.1.0	Last update
Oct.22, 2025	A.1.1	Revise PACKAGE MECHANICAL DATA

PACKAGE MECHANICAL DATA

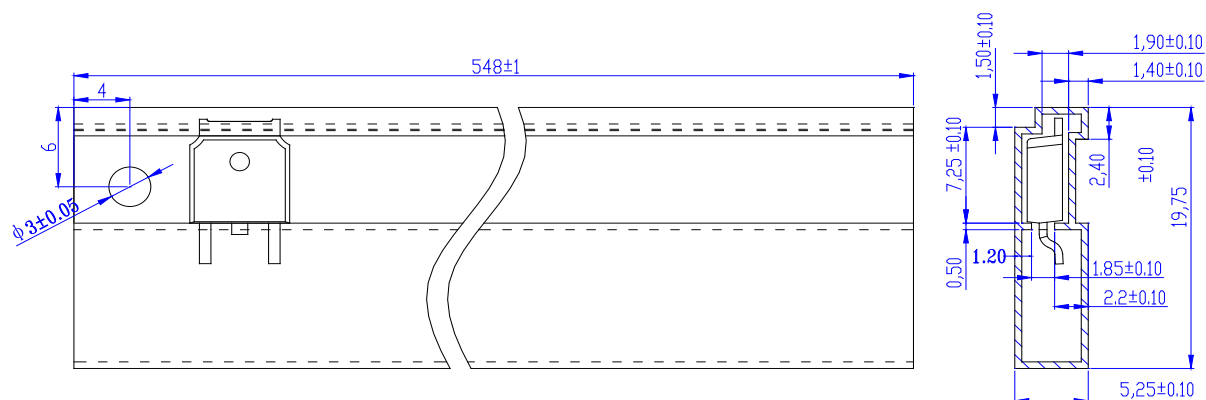


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A1	0.80		1.20	0.031		0.047
A2	0		0.15	0		0.006
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
G1	2.18		2.38	0.086		0.094
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
L3	1.10		1.50	0.043		0.059
M	0.65		0.95	0.026		0.037
N	0.65		0.95	0.026		0.037
O	2.80		3.20	0.110		0.126
P	3.10		3.30	0.122		0.130
V1		7°			7°	
V2	0°		6°	0°		6°

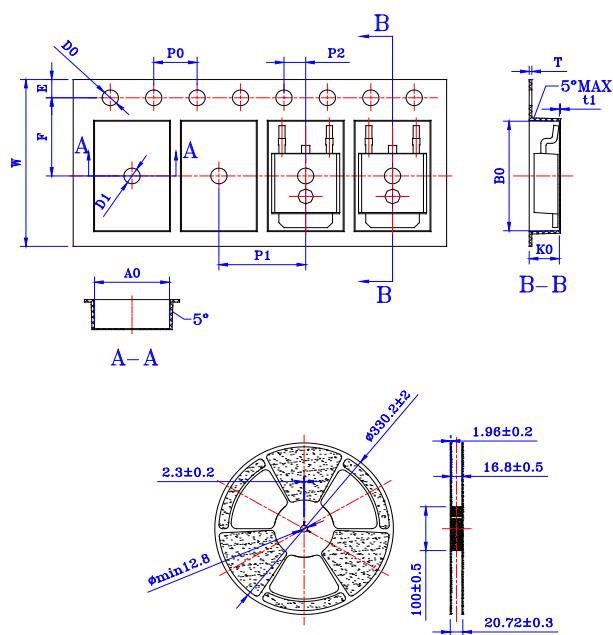
FOOTPRINT-TO-252 (dimensions in mm)



DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-252	TUBE	80	4,000	20,000



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
W	15.90	16.00	16.10	0.626	0.630	0.634
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
D0	1.50	1.55	1.60	0.059	0.060	0.063
D1	1.50	—	—	0.059	—	—
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.90	2.00	2.10	0.075	0.079	0.083
10P0	39.80	40.00	40.20	1.567	1.575	1.583
A0	6.80	6.90	7.00	0.267	0.272	0.276
B0	10.40	10.50	10.60	0.408	0.413	0.417
K0	2.60	2.70	2.80	0.102	0.106	0.110
T	0.25	0.30	0.35	0.010	0.012	0.014
t1	0.10	—	—	0.004	—	—

PACKAGE	OUTLINE	REEL (PCS)	PER CARTON (PCS)	TAPE & REEL
TO-252	TAPING	2,500	25,000	13 inch

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